Technical Data Data Sheet 3469, Rev. A Green Products

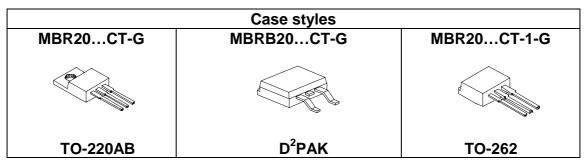
MBR20..CT-G/MBRB20..CT-G/MBR20..CT-1-G SCHOTTKY RECTIFIER

Applications:

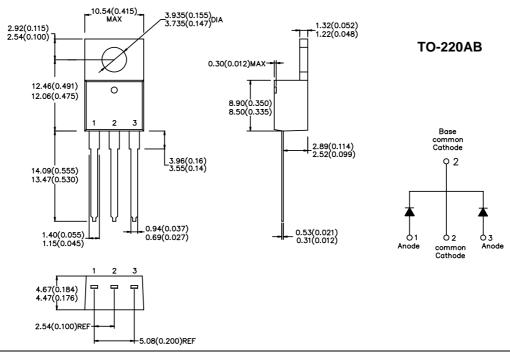
• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

Features:

- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Mechanical Dimensions: In Inches / mm



- 221 West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FAX (631) 242-9798
 - World Wide Web Site http://www.sensitron.com E-Mail Address sales@sensitron.com •

Green Products Technical Data Data Sheet 3469, Rev. A D²PAK 4.69(0.185) BASE COMMON 10.16(0.400) 4.20(0.165) REF. 1.37(0.054) 1.32(0.052) **CATHODE** 1.17(0.046) 1.22(0.048) 8.90(0.350) 15.49(0.610) 8.50(0.335) 14.73(0.580) 1.70(0.067) 5.28(0.208) 1.30(0.051) ANODE 1 ANODE 2 4.78(0.188) COMMON **CATHODE** 0.55(0.022) $3 \times \frac{1.40(0.055)}{1.14(0.045)}$ 0.93(0.037) 0.46(0.018)0.69(0.027) 5.08(0.200)REF. 10.54(0.415) 1.32(0.052) 1.22(0.048) **TO-262** 10.29(0.405) 1.40 (0.055) MAX. 8.76 (0.345) 8.61 (0.339) 24.25(0.955) Base 23.47(0.924) common 3.96(0.156) Cathode 3.55(0.140) 14.09(0.555) Q 2 13.47(0.530) - 0.10(0.004) 1.40(0.055) 0.94(0.037) 2.89(0.114) 1.15(0.045) _ 2.64(0.104) 0.69(0.027) d 2 common Anode Anode Cathode 2.79(0.117) 2.29(0.090)

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5.33(0.210)

4.83(0.190)

4.57(0.180)

4.32(0.170)

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Technical Data Data Sheet 3469, Rev. A Maximum Ratings: **Green Products**

Characteristics	Symbol	Condition		Max.	Units
Peak Inverse Voltage	V_{RWM}	-	35	MBR2035CT-G MBRB2035CT-G MBR2035CT-1-G	\ \
			45	MBR2045CT-G MBRB2045CT-G MBR2045CT-1-G	
Max. Average Forward	. ()		10(per leg)		Α
Current			20(per device)		
Peak Repetitive Forward Current (per leg)	I _{FRM}	Rated V _R , square wave, 20kHz,TC=135°C	20		А
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	220		А
Peak Repetitive Reverse Surge Current	I _{RRM}	2.0 µ sec 1.0kHz	0.7		А

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	@ 20A, Pulse, T _J = 25 °C	0.84	٧
	V_{F2}	@ 20A, Pulse, T _J = 125 °C	0.72	V
Max. Reverse Current (per leg) *	I _{R1}	$@V_R = \text{rated } V_R \text{ Pulse}$ $T_J = 25 ^{\circ}\text{C}$	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$, Pulse $T_J = 125 ^{\circ}\text{C}$	15	mA
Max. Junction Capacitance (per leg)	C _T	$@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz, V_{SIG} = 50(p-p)$	600	pF
Typical Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,00	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Max. Junction Temperature	T_J	-	-55 to +150	°C	
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C	
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	2.0	°C/W	
Typical Thermal Resistance Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased (only for TO-220)	0.50	°C/W	
Approximate Weight	wt	-	2	g	
Mounting Torque	T _M	-	6(Min.) 12(Max.)	Kg-cm	
Case Style	TO-220AB D ² PAK TO-262				

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SENSITRON SEMICONDUCTOR

MBR2035/2045CT-G MBRB2035/2045CT-G MBR2035/2045CT-1-G

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